Fast Recovery Diode Type SA24MI3770Z0



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SA	24	MI	3770	Z	0	
-	Voltage Code	MQ = standard capsule MI = rupture rated capsule	Current code	Type code	Special code	Optional code

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Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	2400	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	2500	V
V _{RDC}	Maximum reverse D.C. Voltage, (note 1)	1450	V
note 1)	De-Rating factor of 0.13% per °C is applicable for T _j below 25°C		

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
I _{F(AV)M}	Maximum average forward current, T _{sink} = 55°C, (note 1)	3770	А
I _{F(AV)M}	Maximum average forward current, T _{sink} = 100°C, (note 1)	2402	Α
I _{F(AV)M}	Maximum average forward current, T _{sink} = 100°C, (note 2)	1416	Α
I _{F(RMS)}	Nominal RMS forward current, T _{sink} = 25°C (note 1)	7109	Α
I _{f(d.c.)}	D.C. forward current, T _{sink} = 25°C (note 3)	5991	А
I _{FSM}	Peak non-repetitive surge current t_p = 10ms, V_{RM} = 60% V_{RRM} , (note 4)	44.0	kA
I _{FSM2}	Peak non-repetitive surge current t_p = 10ms, $V_{RM} \le$ 10V, (note 4)	48.4	kA
l ² t	I^2 t capacity for fusing $t_p = 10$ ms, $V_{RM} = 60\%V_{RRM}$, (note 4)	9.68 · 10 ⁶	A^2s
l ² t	I^2 t capacity for fusing t_p = 10ms, $V_{RM} \le 10V$, (note 4)	11.7 · 10 ⁶	A^2s
T _{jop}	Operating temperature range	-40 to +150	°C
T _{stg}	Storage temperature range	-55 to +150	°C
note 1)	Double-side cooled, single phase, 50Hz, 180° half-sinewave.		
note 2)	Single-side cooled, single phase, 50Hz, 180° half-sinewave.		
note 3)	Double-side cooled.		
note 4)	Half-sinewave, 150°C T _j initial.		



Characteristics

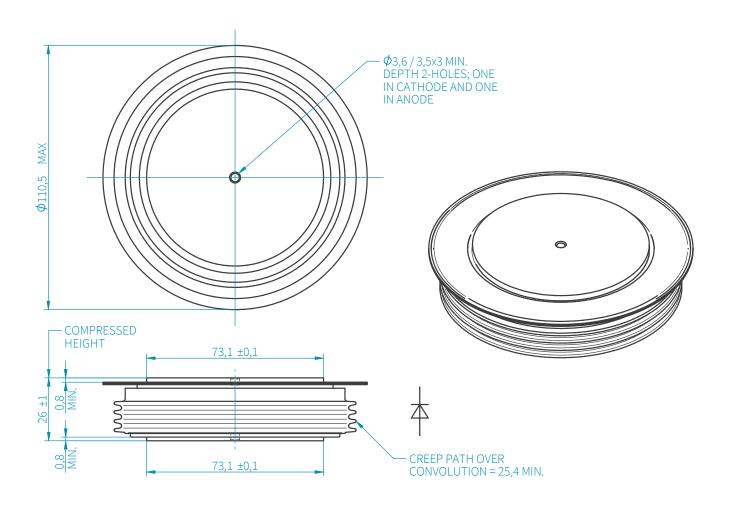
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
V _{FM}	Maximum peak forward voltage	I _{FM} =4700A	-	-	1.74	V
	Maximum peak forward voltage	I _{FM} =7500A	-	-	2.05	V
V_{T0}	Threshold Voltage		-	-	1.190	V
r_{T}	Slope resistance		-	-	0.118	mΩ
V_{FRM}	Maximum forward recovery voltage	di/dt = 1000A/μs, T _j = 25°C	-	-	18	V
		di/dt = 1000A/μs	-	-	24	V
I _{RRM}	Peak reverse current	Rated V _{RRM}	-	-	150	mA
Q_{rr}	Recovered charge		-	2000	-	μC
Q _{ra}	Recovered charge, 50% Chord	$I_{FM} = 1000A$, $t_p = 1000 \mu s$, $di/dt = 60A/\mu s$, $V_R = 50V$,	-	1100	330	μC
I _{rm}	Reverse recovery current	50% Chord.	-	320	-	А
t _{rr}	Reverse recovery time, 50% Chord		-	7	-	μs
R _{th.JK}	Thermal resistance, junction to heatsink	Double side cooled	-	-	0.011	K/W
rtnJK		Single side cooled	-	-	0.022	K/W
F	Mounting force	note 2)	27	-	47	kN
W_t	Weight		-	1700	-	g
note 1)	Unless otherwise indicated T _j = 150°C					
note 2)	For other clamp forces consult factory					

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